Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Plastic **Overall Length:** Between 0.280 inches and 0.320 inches **Overall Height:** Between 0.175 inches and 0.185 inches **Overall Width:** Between 0.240 inches and 0.260 inches **Mounting Facility Quantity:** 1 Internal Configuration: Junction contact Electrode Internally-electrically Connected To Case: Anode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakover voltage, dc **Current Rating Per Characteristic:** 4.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0